

## 0.9 V to 2.5 V, 55 mΩ Load Switch in WCSP4

### DESCRIPTION

SiP32451, SiP32452, and SiP32453 are n-channel integrated high side load switches that operate from 0.9 V to 2.5 V input voltage range.

SiP32451, SiP32452, and SiP32453 have low input logic control threshold that can interface with low voltage control GPIO directly without extra level shift or driver. There is a pull down at this EN logic control pin.

Turn on time is fast, less than 25 μs typically for input voltage of 1.2 V or higher. SiP32451 and SiP32452 have fast turn off delay time of less than 1 μs while SiP32453 features a guaranteed turn off delay of greater than 30 μs, typically 90 μs.

SiP32451 features an output discharge for fast turn off. SiP32451, SiP32452, and SiP32453 are available in compact wafer level CSP package, WCSP4 0.8 mm x 0.8 mm with 0.4 mm pitch.

### FEATURES

- Low input voltage, 0.9 V to 2.5 V
- Low  $R_{ON}$ , 55 mΩ typical
- Fast turn on time
- Low logic control with hysteresis
- Reverse current blocking when disabled
- Integrated pull down at EN pin
- Output discharge (SiP32451)
- 4 bump WCSP 0.8 mm x 0.8 mm with 0.4 mm pitch package
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**  
Available

### APPLICATIONS

- Battery operated devices
- Smart phones
- GPS and PMP
- Computer
- Medical and healthcare equipment
- Industrial and instrument
- Cellular phones and portable media players
- Game console

### TYPICAL APPLICATION CIRCUIT

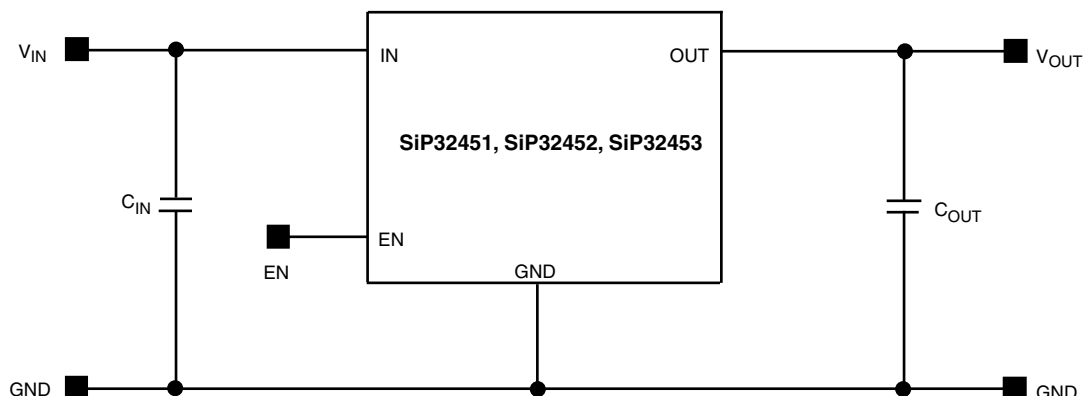


Fig. 1 - SiP32451, SiP32452, and SiP32453 Typical Application Circuit

### ORDERING INFORMATION

TEMPERATURE RANGE	PACKAGE	MARKING	PART NUMBER
-40 °C to +85 °C	WCSP4: 4 bumps (2 x 2, 0.4 mm pitch, 208 μm bump height, 0.8 mm x 0.8 mm die size)	AA	SiP32451DB-T2-GE1
		AB	SiP32452DB-T2-GE1
		AC	SiP32453DB-T2-GE1

#### Note

- GE1 denotes halogen-free and RoHS-compliant

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	LIMIT	UNIT
Supply input voltage ( $V_{IN}$ )	-0.3 to +2.75	V
Enable input voltage ( $V_{EN}$ )	-0.3 to +2.75	
Output voltage ( $V_{OUT}$ )	-0.3 to +2.75	
Maximum continuous switch current ( $I_{max}$ )	1.2	A
Maximum pulsed current ( $I_{DM}$ ) $V_{IN}$ (pulsed at 1 ms, 10 % duty cycle)	2	
ESD rating (HBM)	4000	V
Junction temperature ( $T_J$ )	-40 to +150	°C
Thermal resistance ( $\theta_{JA}$ ) <sup>a</sup>	280	°C/W
Power dissipation ( $P_D$ ) <sup>a</sup>	196	mW

**Notes**

- a. Device mounted with all leads and power pad soldered or welded to PC board  
b. Derate 3.6 mW/°C above  $T_A = 70^\circ\text{C}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating/conditions for extended periods may affect device reliability.

**RECOMMENDED OPERATING RANGE**

PARAMETER	LIMIT	UNIT
Input voltage range ( $V_{IN}$ )	0.9 to 2.5	V
Operating junction temperature range	-40 to +125	°C

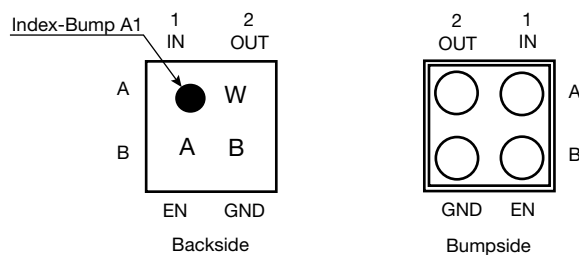
**SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS SPECIFIED $V_{IN} = 1\text{ V}$ , $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ (typical values are at $T_A = 25^\circ\text{C}$ )	LIMITS			UNIT
			MIN. <sup>a</sup>	TYP. <sup>b</sup>	MAX. <sup>a</sup>	
Operating voltage <sup>c</sup>	$V_{IN}$		0.9	-	2.5	V
Quiescent current	$I_Q$	$V_{IN} = 1.2\text{ V}$ , $V_{EN} = V_{IN}$ , OUT = open	-	10	15	$\mu\text{A}$
		$V_{IN} = 2.5\text{ V}$ , $V_{EN} = V_{IN}$ , OUT = open	-	34	60	
Off supply current	$I_{Q(off)}$	SiP32451	-	-	30	
		SiP32452, SiP32453	-	-	1	
Off switch current	$I_{DS(off)}$	EN = GND, OUT = 0 V	-	-	30	
Reverse blocking current	$I_{RB}$	$V_{OUT} = 2.5\text{ V}$ , $V_{IN} = 0.9\text{ V}$ , $V_{EN} = 0\text{ V}$	-	0.001	10	
On-resistance	$R_{DS(on)}$	$V_{IN} = 1\text{ V}$ , $I_L = 200\text{ mA}$ , $T_A = 25^\circ\text{C}$	-	56	65	m $\Omega$
		$V_{IN} = 1.2\text{ V}$ , $I_L = 200\text{ mA}$ , $T_A = 25^\circ\text{C}$	-	55	65	
		$V_{IN} = 1.8\text{ V}$ , $I_L = 200\text{ mA}$ , $T_A = 25^\circ\text{C}$	-	54	65	
		$V_{IN} = 2.5\text{ V}$ , $I_L = 200\text{ mA}$ , $T_A = 25^\circ\text{C}$	-	54	65	
On-resistance temp. coefficient	$TC_{RDS}$		-	3900	-	ppm/°C
Output pull-down resistance	$R_{PD}$	$V_{EN} = 0\text{ V}$ , $T_A = 25^\circ\text{C}$ (SiP32451 only)	-	425	550	$\Omega$
EN input low voltage <sup>c</sup>	$V_{IL}$	$V_{IN} = 1\text{ V}$	-	-	0.1	V
EN input high voltage <sup>c</sup>	$V_{IH}$	$V_{IN} = 2.5\text{ V}$	1.5	-	-	
EN input leakage	$I_{EN}$	$V_{IN} = 2.5\text{ V}$ , $V_{EN} = 0\text{ V}$	-	-	1	$\mu\text{A}$
		$V_{IN} = 2.5\text{ V}$ , $V_{EN} = 2.5\text{ V}$	-	10	15	

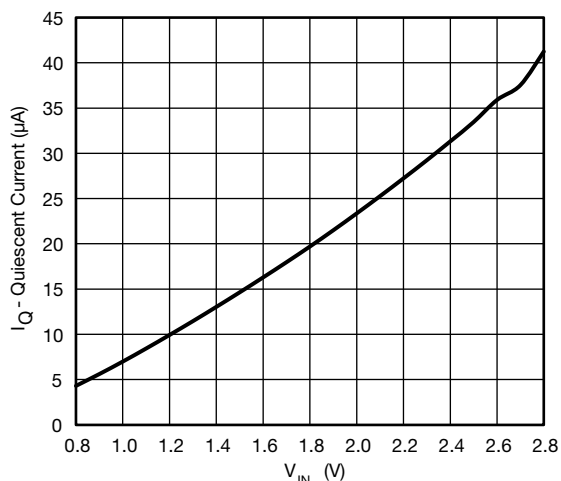
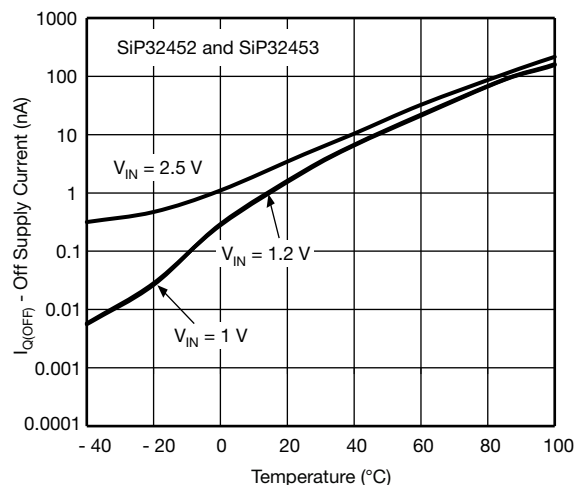
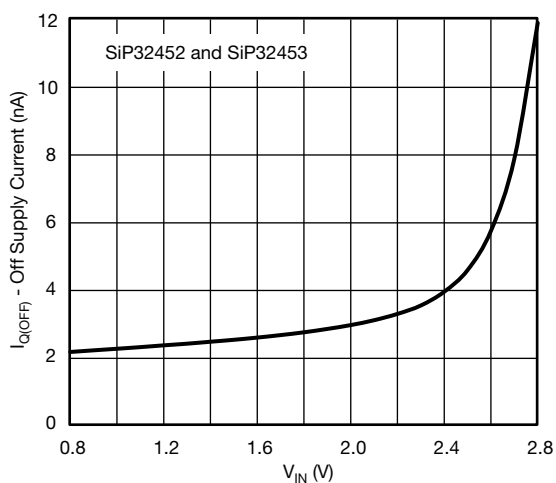
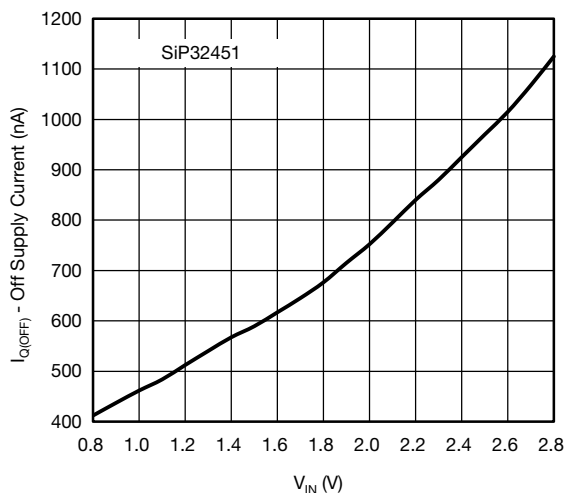
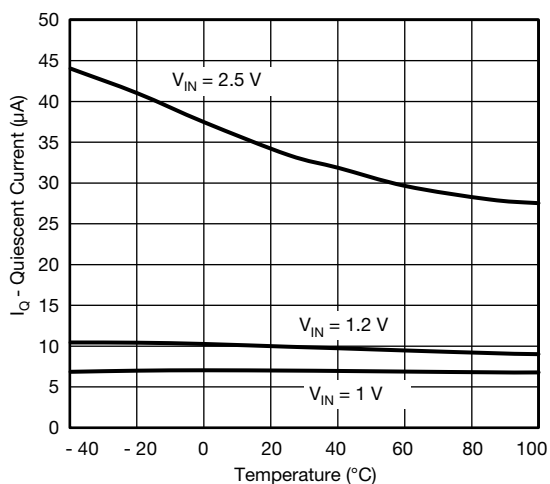
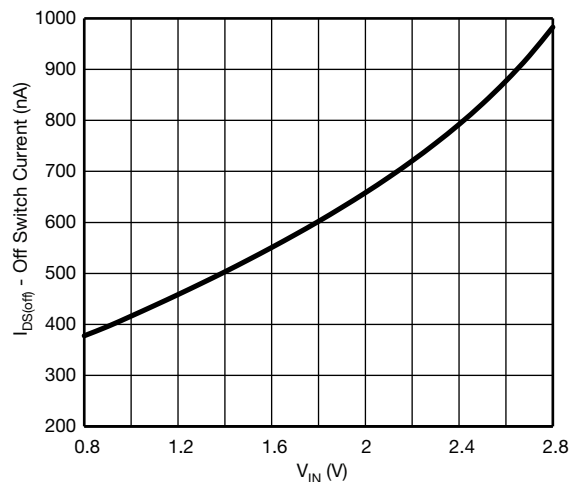
SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS SPECIFIED $V_{IN} = 1\text{ V}$ , $T_A = -40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ (typical values are at $T_A = 25\text{ }^{\circ}\text{C}$ )		LIMITS		
				MIN. <sup>a</sup>	TYP. <sup>b</sup>	MAX. <sup>a</sup>
Output turn-on delay time	$t_{d(on)}$	$V_{IN} = 1.2\text{ V}$	$R_{LOAD} = 10\text{ }\Omega$ , $C_L = 0.1\text{ }\mu\text{F}$ , $T_A = 25\text{ }^{\circ}\text{C}$	-	0.4	1
		$V_{IN} = 2.5\text{ V}$		-	0.05	1
Output turn-on rise time	$t_r$	$V_{IN} = 1.2\text{ V}$		10	20	30
		$V_{IN} = 2.5\text{ V}$		5	9.8	20
Output turn-off delay time	$t_{d(off)}$	SiP32451, SiP32452 $V_{IN} = 1.2\text{ V}$		-	0.25	1
		SiP32451, SiP32452 $V_{IN} = 2.5\text{ V}$		-	0.15	1
		SiP32453, $V_{IN} = 1.2\text{ V}$		30	98	150
		SiP32453, $V_{IN} = 2.5\text{ V}$		30	86	150

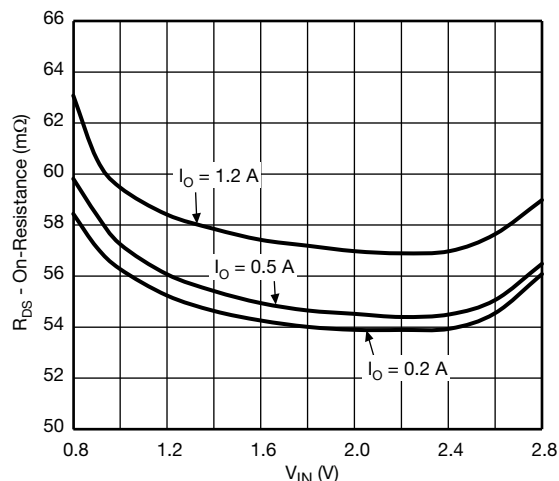
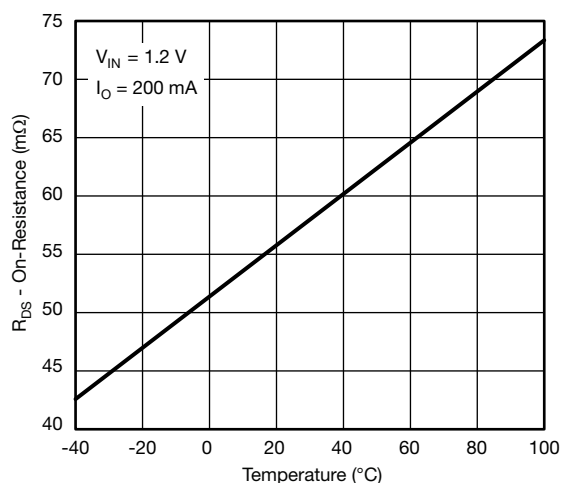
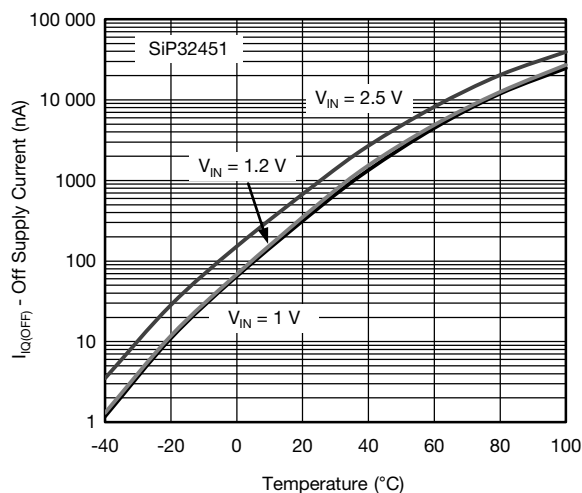
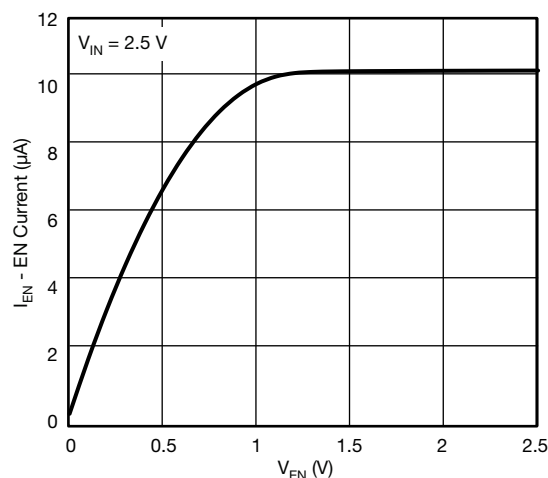
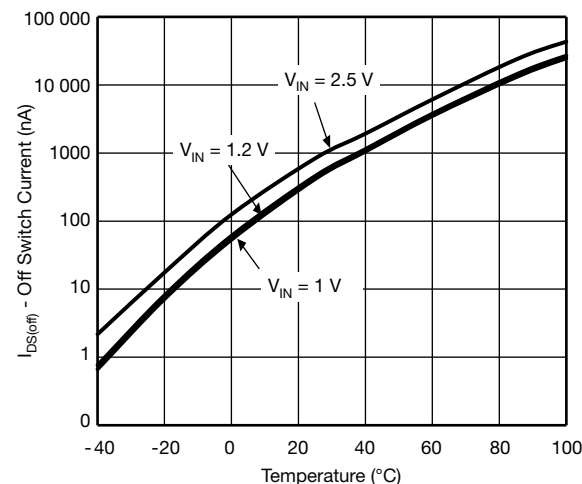
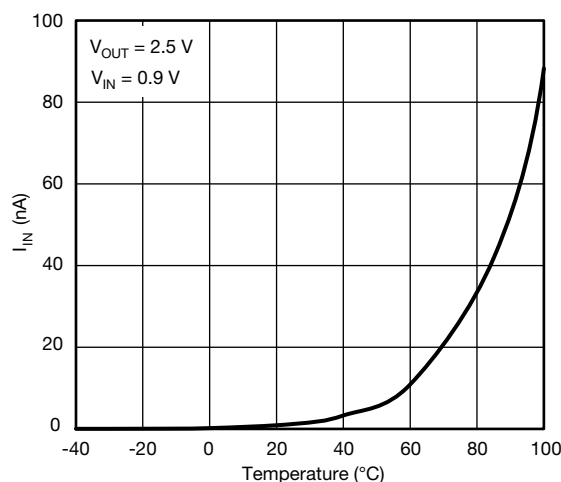
**Notes**

- a. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum  
b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing  
c. For  $V_{IN}$  outside this range consult typical EN threshold curve

**PIN CONFIGURATION**

**Fig. 2 - WCSP4 2 x 2 Package**

PIN DESCRIPTION		
PIN NUMBER	NAME	FUNCTION
A1	IN	This pin is the n-channel MOSFET drain connection. Bypass to ground through a 4.7 $\mu\text{F}$ capacitor
A2	OUT	This pin is the n-channel MOSFET source connection. Bypass to ground through a 0.1 $\mu\text{F}$ capacitor
B1	EN	Enable input
B2	GND	Ground connection

**TYPICAL CHARACTERISTICS** (internally regulated, 25 °C, unless otherwise noted)

**Fig. 3 - Quiescent Current vs. Input Voltage**

**Fig. 6 - Off Supply Current vs. Temperature**

**Fig. 4 - Off Supply Current vs. Input Voltage**

**Fig. 7 - Off Supply Current vs. Input Voltage**

**Fig. 5 - Quiescent Current vs. Temperature**

**Fig. 8 - Off Switch Current vs. Input Voltage**

**TYPICAL CHARACTERISTICS** (internally regulated, 25 °C, unless otherwise noted)

**Fig. 9 -  $R_{DS(on)}$  vs.  $V_{IN}$** 

**Fig. 12 -  $R_{DS(on)}$  vs. Temperature**

**Fig. 10 - Off Supply Current vs. Temperature**

**Fig. 13 -  $I_{EN}$  vs.  $V_{EN}$** 

**Fig. 11 - Off Switch Current vs. Temperature**

**Fig. 14 - Reverse Blocking Current vs. Temperature**



**TYPICAL CHARACTERISTICS** (internally regulated, 25 °C, unless otherwise noted)

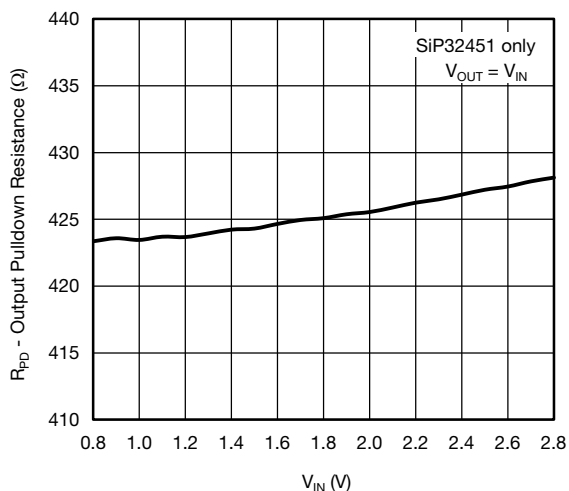


Fig. 15 - Output Pull-down Resistance vs. Input Voltage

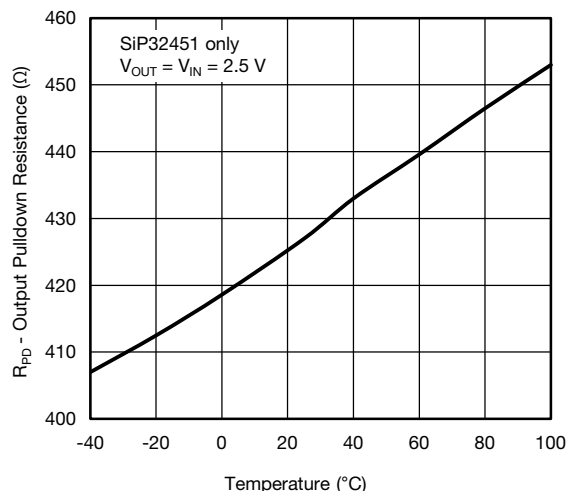


Fig. 18 - Output Pull-down Resistance vs. Temperature

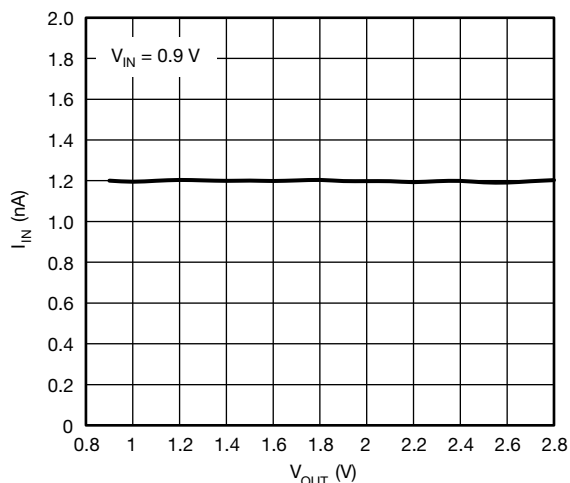


Fig. 16 - Reverse Blocking Current vs. Output Voltage

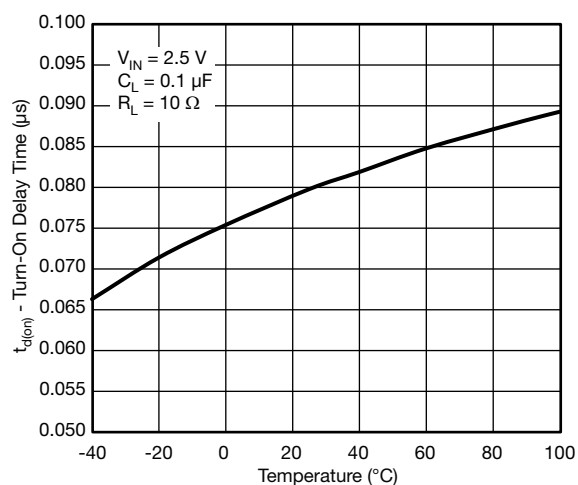


Fig. 19 - Turn-On Delay Time vs. Temperature

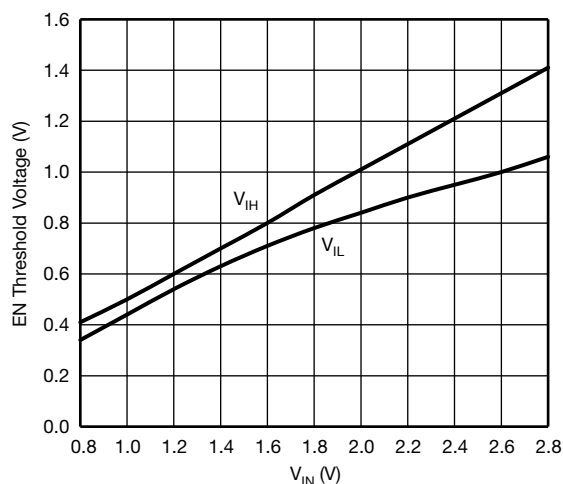


Fig. 17 - EN Threshold Voltage vs. Input Voltage

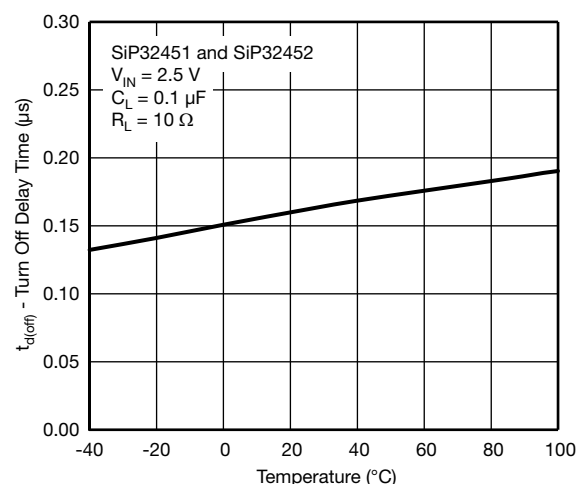


Fig. 20 - Turn-Off Delay Time vs. Temperature



## TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

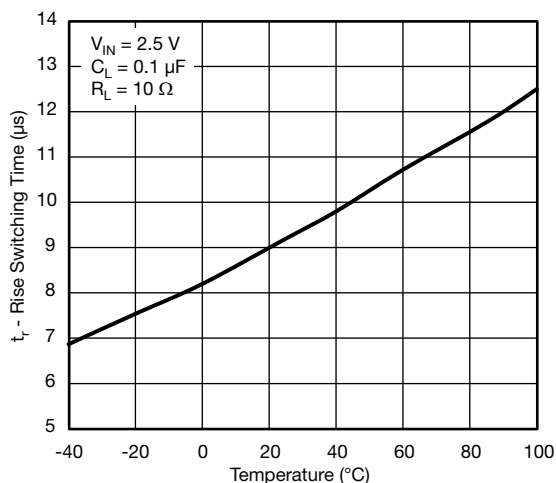


Fig. 21 - Rise Time vs. Temperature

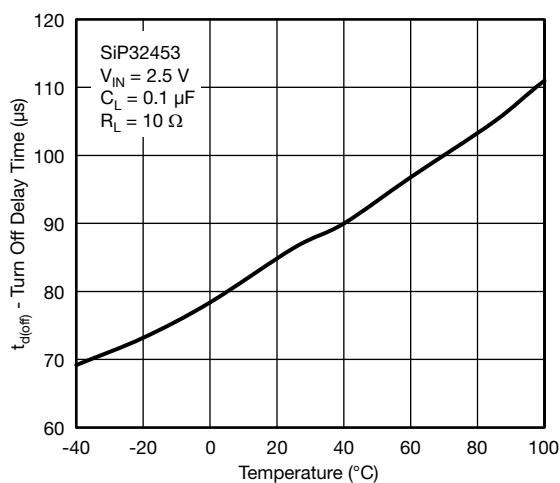


Fig. 22 - Turn-Off Delay Time vs. Temperature

## TYPICAL WAVEFORMS

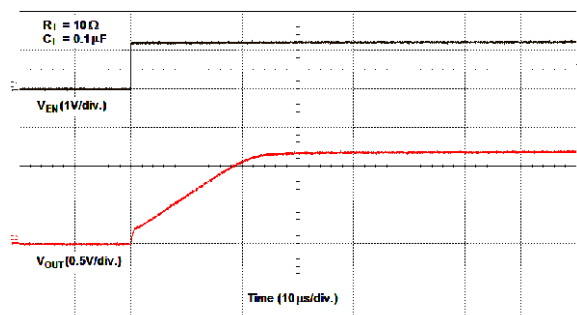


Fig. 23 - Turn-On Time ( $V_{IN} = 1.2 V$ )

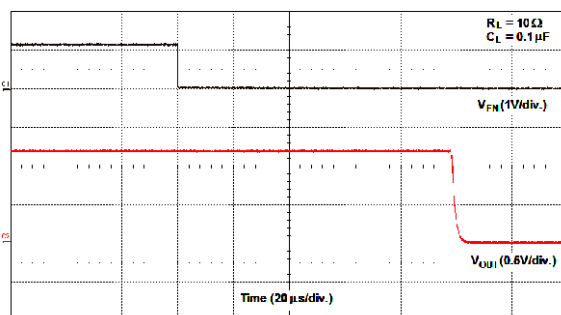


Fig. 25 - SiP32453 Turn-Off Time ( $V_{IN} = 1.2 V$ )

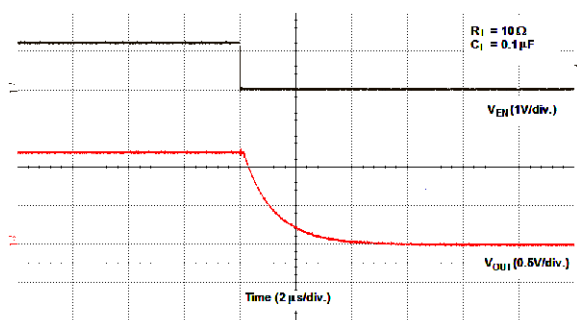


Fig. 24 - SiP32451 and SiP32452 Turn-Off Time ( $V_{IN} = 1.2 V$ )

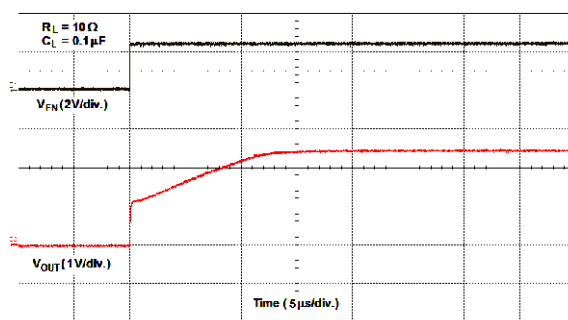


Fig. 26 - Turn-On Time ( $V_{IN} = 2.5 V$ )

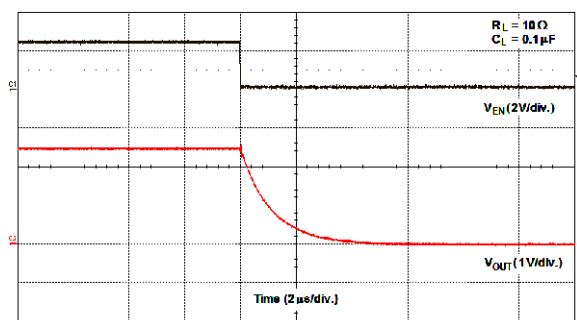


Fig. 27 - SiP32451 and SiP32452 Turn-Off Time ( $V_{IN} = 2.5\text{ V}$ )

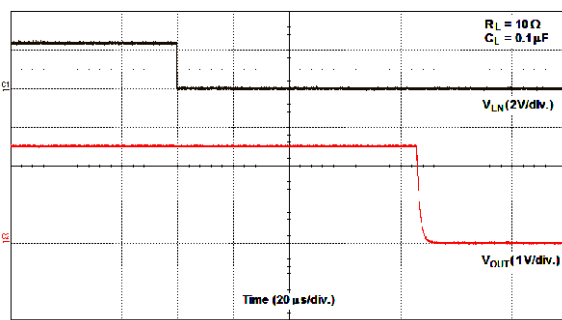


Fig. 28 - SiP32453 Turn-Off Time ( $V_{IN} = 2.5\text{ V}$ )

## BLOCK DIAGRAM

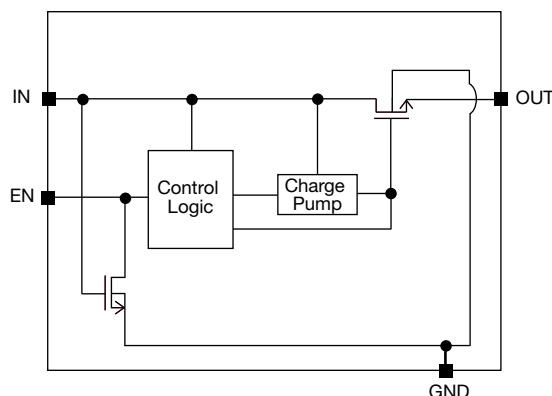


Fig. 29 - Functional Block Diagram

## DETAILED DESCRIPTION

SiP32451, SiP32452, and SiP32453 are n-channel power MOSFET designed as high side load switch. Once enable the device charge pumps the gate of the power MOSFET to a constant gate to source voltage for fast turn on time. The mostly constant gate to source voltage keeps the on resistance low through out the input voltage range. When disable, the SiP32451 and SiP32452 pull the gate of the output n-channel low right away for a fast turn off delay while there is a build-in turn off delay for the SiP32453. The SiP32451 especially features a output discharge circuit to help discharge the output capacitor. The turn off delay for the SiP32453 is guaranteed to be at least 30  $\mu\text{s}$ . Because the body of the output n-channel is always connected to GND, it prevents the current from going back to the input in case the output voltage is higher than the output.

## APPLICATION INFORMATION

### Input Capacitor

While a bypass capacitor on the input is not required, a 4.7  $\mu\text{F}$  or larger capacitor for  $C_{IN}$  is recommended in almost all applications. The bypass capacitor should be placed as physically close as possible to the input pin to be effective in minimizing transients on the input. Ceramic capacitors are recommended over tantalum because of

their ability to withstand input current surges from low impedance sources such as batteries in portable devices.

### Output Capacitor

A 0.1  $\mu\text{F}$  capacitor across  $V_{OUT}$  and GND is recommended to insure proper slew operation. There is inrush current through the output MOSFET and the magnitude of the inrush current depends on the output capacitor, the bigger the  $C_{OUT}$  the higher the inrush current. There are no ESR or capacitor type requirement.

### Enable

The EN pin is compatible with CMOS logic voltage levels. It requires at least 0.1 V or below to fully shut down the device and 1.5 V or above to fully turn on the device.

### Protection Against Reverse Voltage Condition

SiP32451, SiP32452, and SiP32453 can block the output current from going to the input in case where the output voltage is higher than the input voltage when the main switch is off.

### Thermal Considerations

These devices are designed to maintain a constant output load current. Due to physical limitations of the layout and assembly of the device the maximum switch current is 1.2 A as stated in the Absolute Maximum Ratings table. However,





another limiting characteristic for the safe operating load current is the thermal power dissipation of the package. To obtain the highest power dissipation (and a thermal resistance of 280 °C/W) the device should be connected to a heat sink on the printed circuit board.

The maximum power dissipation in any application is dependent on the maximum junction temperature,  $T_J$  (max.) = 125 °C, the junction-to-ambient thermal resistance,  $\theta_{JA}$  = 280 °C/W, and the ambient temperature,  $T_A$ , which may be formulaically expressed as:

$$P \text{ (max.)} = \frac{T_{J(\text{max.})} - T_A}{\theta_{JA}} = \frac{125 - T_A}{280}$$

It then follows that, assuming an ambient temperature of 70 °C, the maximum power dissipation will be limited to about 196 mW.

So long as the load current is below the 1.2 A limit, the maximum continuous switch current becomes a function two things: the package power dissipation and the  $R_{DS(on)}$  at the ambient temperature.

As an example let us calculate the worst case maximum load current at  $T_A$  = 70 °C. The worst case  $R_{DS(on)}$  at 25 °C is

65 mΩ. The  $R_{DS(on)}$  at 70 °C can be extrapolated from this data using the following formula:

$$R_{DS(on)} \text{ (at 70 °C)} = R_{DS(on)} \text{ (at 25 °C)} \times (1 + T_C \times \Delta T)$$

Where  $T_C$  is 3900 ppm/°C. Continuing with the calculation we have

$$R_{DS(on)} \text{ (at 70 °C)} = 65 \text{ m}\Omega \times (1 + 0.0039 \times (70 \text{ °C} - 25 \text{ °C})) \\ = 76.4 \text{ m}\Omega$$

The maximum current limit is then determined by

$$I_{LOAD(\text{max.})} < \sqrt{\frac{P \text{ (max.)}}{R_{DS(on)}}}$$

which in this case is 1.6 A. Under the stated input voltage condition, if the 1.6 A current limit is exceeded the internal die temperature will rise and eventually, possibly damage the device.

To avoid possible permanent damage to the device and keep a reasonable design margin, it is recommended to operate the device maximum up to 1.2 A only as listed in the Absolute Maximum Ratings table.

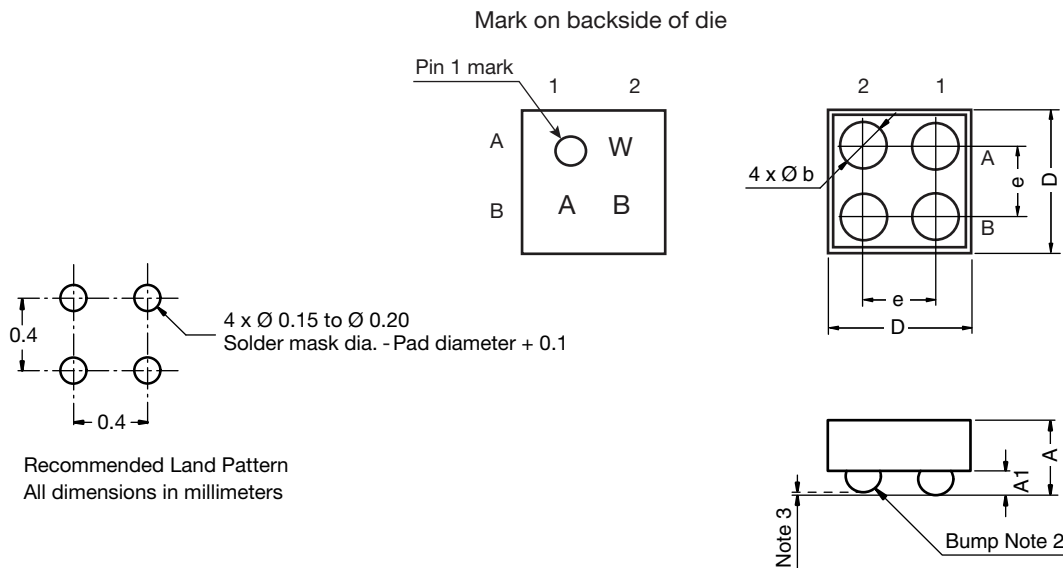
**PRODUCT SUMMARY**

Part number	SiP32451	SiP32452	SiP32453
Description	0.9 V to 2.5 V, 55 mΩ, bidirectional off isolation, fast turn on / off, output discharge	0.9 V to 2.5 V, 55 mΩ, bidirectional off isolation, fast turn on / off	0.9 V to 2.5 V, 55 mΩ, bidirectional off isolation, fast turn on and 98 μs turn off delay
Configuration	Single	Single	Single
Slew rate time (μs)	20	20	20
On delay time (μs)	0.4	0.4	0.4
Input voltage min. (V)	0.9	0.9	0.9
Input voltage max. (V)	2.5	2.5	2.5
On-resistance at input voltage min. (mΩ)	56	56	56
On-resistance at input voltage max. (mΩ)	54	54	54
Quiescent current at input voltage min. (μA)	4	4	4
Quiescent current at input voltage max. (μA)	32	32	32
Output discharge (yes / no)	Yes	No	No
Reverse blocking (yes / no)	Yes	Yes	Yes
Continuous current (A)	1.2	1.2	1.2
Package type	WCSP4	WCSP4	WCSP4
Package size (W, L, H) (mm)	0.8 x 0.8 x 0.5	0.8 x 0.8 x 0.5	0.8 x 0.8 x 0.5
Status code	2	2	2
Product type	Slew rate	Slew rate	Slew rate
Applications	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable

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## WCSP4: 4 Bumps

(2 x 2, 0.4 mm pitch, 208 µm bump height, 0.8 mm x 0.8 mm die size)



DWG-No: 6004

### Notes

- (1) Laser mark on the backside surface of die
- (2) Bumps are SAC396
- (3) 0.05 max. coplanarity

DIM.	MILLIMETERS <sup>a</sup>			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.515	0.530	0.545	0.0203	0.0209	0.0215
A1	0.208			0.0082		
b	0.250	0.260	0.270	0.0098	0.0102	0.0106
e	0.400			0.0157		
D	0.720	0.760	0.800	0.0283	0.0299	0.0315

### Note

- a. Use millimeters as the primary measurement



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